

Silicon NPN Power Transistors

2SD1236L

DESCRIPTION

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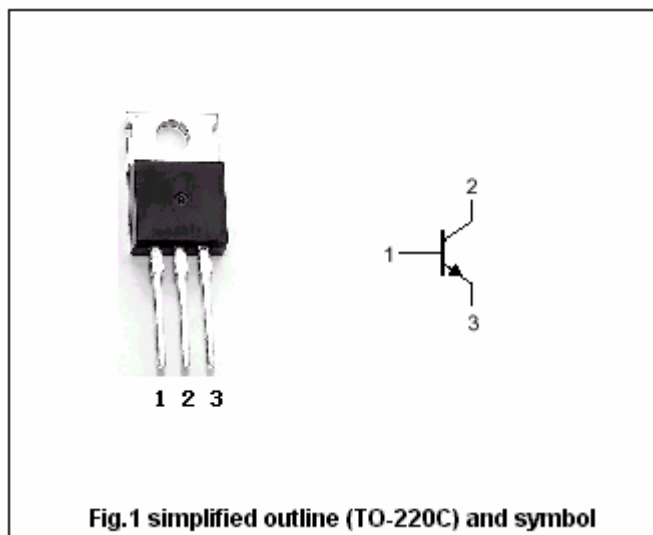
- With TO-220C package
- Complement to type 2SB920L
- Low collector saturation voltage
- Large current capacity.

APPLICATIONS

- Relay drivers,high speed inverters, converters,and other general high-current switching applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter



Absolute maximum ratings(Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V _{CBO}	Collector-base voltage	Open emitter	90	V
V _{CEO}	Collector-emitter voltage	Open base	80	V
V _{EBO}	Emitter-base voltage	Open collector	6	V
I _C	Collector current (DC)		5	A
I _{CM}	Collector current-peak		9	A
P _C	Collector dissipation	T _C =25°C	30	W
			1.75	
T _j	Junction temperature		150	°C
T _{stg}	Storage temperature		-55~150	°C

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CHARACTERISTICS

T_j=25°C unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =1mA ; R _{BE} =∞	80			V
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =1mA ; I _E =0	90			V
V _{(BR)EBO}	Emitter-base breakdown voltage	I _E =1mA ; I _C =0	6			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =3A ; I _B =0.3A			0.4	V
I _{CBO}	Collector cut-off current	V _{CB} =80V ; I _E =0			100	μA
I _{EBO}	Emitter cut-off current	V _{EB} =4V ; I _C =0			100	μA
h _{FE-1}	DC current gain	I _C =1A ; V _{CE} =2V	70		280	
h _{FE-2}	DC current gain	I _C =3A ; V _{CE} =2V	30			
f _T	Transition frequency	I _C =1A ; V _{CE} =5V		20		MHz

Switching times

t _{on}	Turn-on time	I _C =10I _{B1} =-10I _{B2} =2A V _{CC} =50V, R _L =25Ω		0.1		μs
t _s	Storage time			1.2		μs
t _f	Fall time			0.4		μs

◆ h_{FE-1} Classifications

Q	R	S
70-140	100-200	140-280

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PACKAGE OUTLINE

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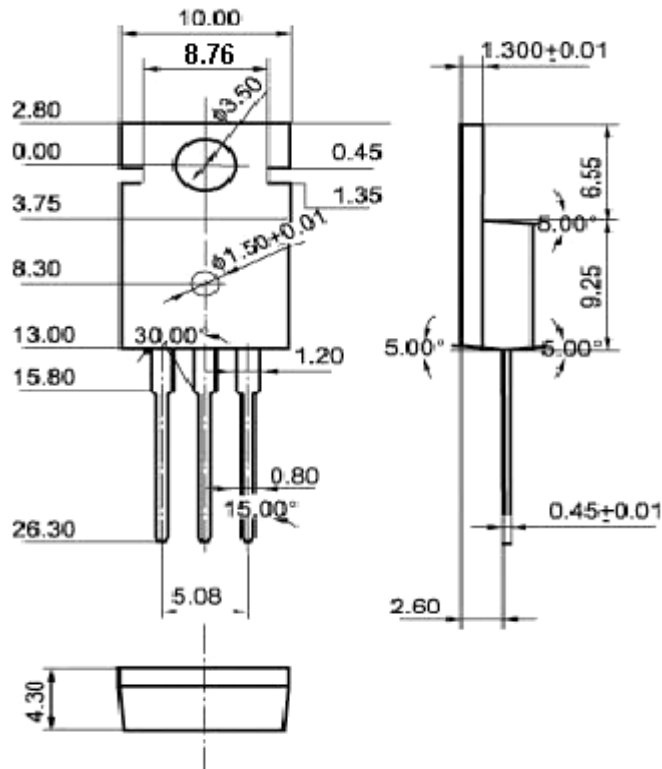


Fig.2 Outline dimensions (unindicated tolerance:±0.10mm)

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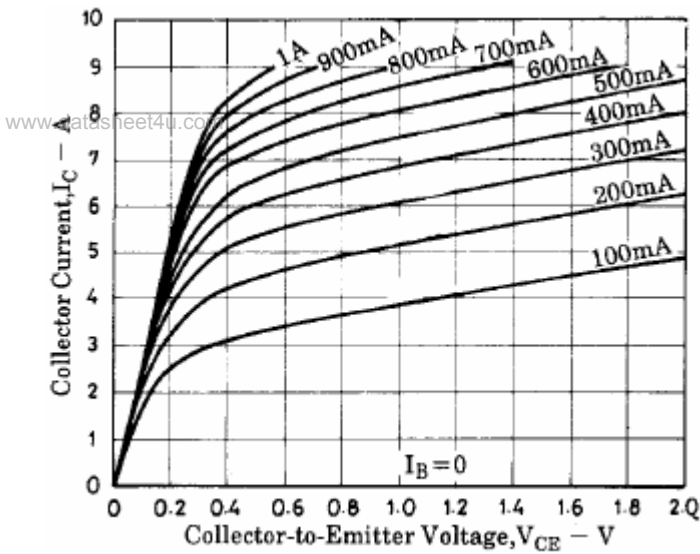


Fig.3 Static Characteristic

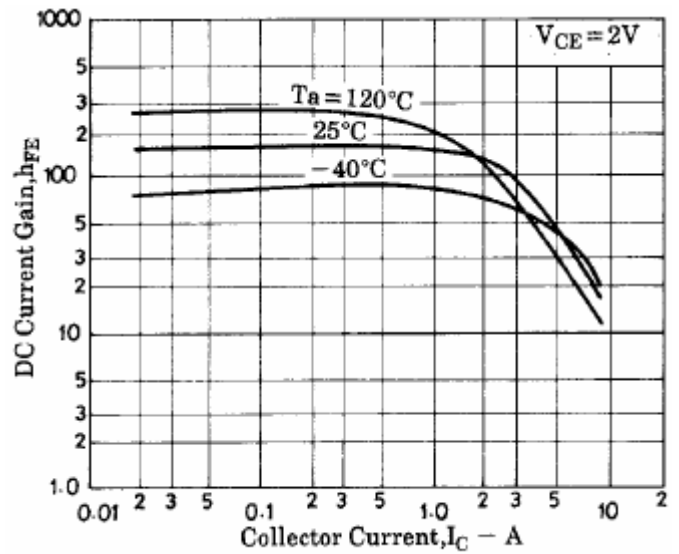


Fig.4 DC current Gain

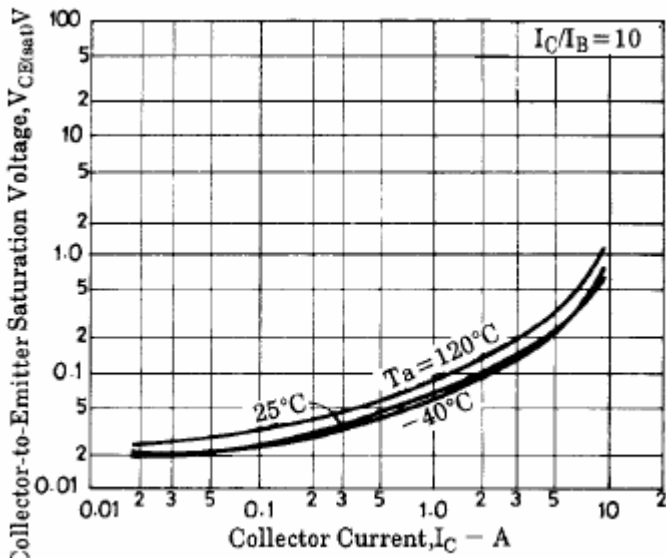


Fig.5 Collector-Emmitter Saturation Voltage

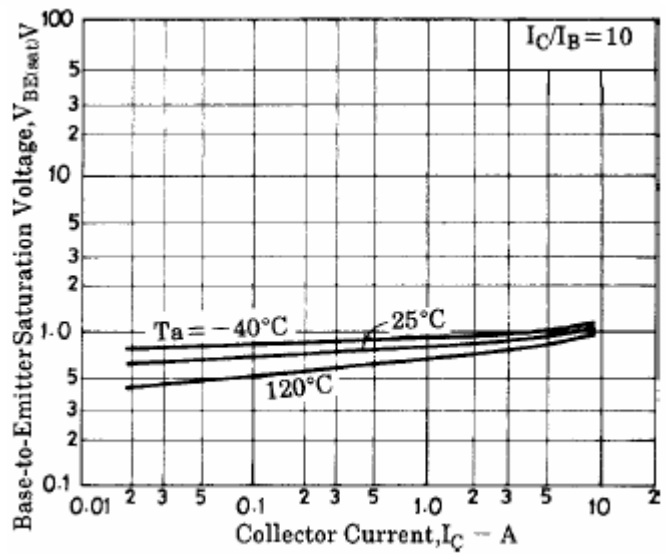


Fig.6 Base-Emmitter Saturation Voltage

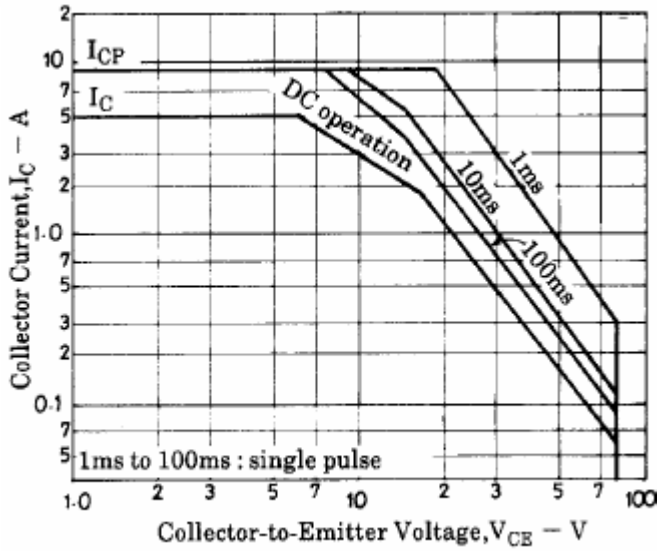


Fig.7 Safe Operating Area